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Table of contents

Volume 993

**19th Russian Youth Conference on Physics of Semiconductors and Nanostructures,
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Preface

[19th Russian Youth Conference on Physics of Semiconductors and Nanostructures, Opto-
and Nanoelectronics](#)

[Peer review statement](#)

Papers

Bulk properties of semiconductors

[Polarization anisotropy of electroluminescence in indium antimonide](#)

I S Makhov, V Yu Panevin, D A Firsov, L E Vorobjev and M Ya Vinnichenko.....1

[Incoherent interlayer transport in single-crystal films of \$Nd_{2-x}Ce_xCuO_4/SrTiO_3\$](#)

A S Klepikova, D S Petukhov, O E Petukhova, T B Charikova, N G Shelushinina and A A Ivanov.....5

[\$MgFe_2O_4\$ phase effect on magnetic properties of \$BiFeO_3\$ in ceramic composites of \$\(1-x\) BiFeO_3-x MgFe_2O_4\$](#)

A A Kamynin, M V Khakhlenkov, N A Tolstykh, A I Bocharov and S A Gridnev.....11

Effect of bismuth substitution for lead in CsPbBr₃ perovskite

M V Elizarov, O V Lozkina, D I Yeletz, A V Emeline, V K Ryabchuk and A A Murashkina.....17

Measuring the distribution of the charge carrier concentration in delta-doped layers based on diamond

L M Shestakova and V I Zubkov.....22

Determination of the energy structure of recombination centers in heavily doped Al_xGa_{1-x}N:Si epitaxial layers with x > 0.5

I V Osinnykh, T V Malin and K S Zhuravlev.....25

Structure growth, surface and interfaces

Photoemission properties of flat and rough GaAs surfaces with cesium and oxygen layers

A G Zhuravlev, D M Kazantsev, V S Khoroshilov, A S Kozhukhov and V L Alperovich.....31

The effects of GaN nanocolumn arrays and thin Si_xN_y buffer layers on the morphology of GaN layers grown by plasma-assisted molecular beam epitaxy on Si(111) substrates

K Yu Shubina, E V Pirogov, A M Mizerov, E V Nikitina and A D Bouravleuv.....37

Zinc oxide hierarchical nanostructures for photocatalysis

O Yukhnovets, A A Semenova, E A Levkevich, A I Maximov and V A Moshnikov.....42

Optimization of conditions for thermal smoothing GaAs surfaces

I O Akhundov, D M Kazantsev, A S Kozhuhov and V L Alperovich.....46

Influence of GaAs substrate properties on the congruent evaporation temperature

A A Spirina, A G Nastovjak and N L Shwartz.....52

Experimental study of surface plasmon-phonon polaritons in GaAs-based microstructures

A I Galimov, V A Shalygin, M D Moldavskaya, V Yu Panevin, G A Melentyev, A A Artemyev, D A Firsov, L E Vorobjev, G V Klimko, A A Usikova, T A Komissarova, I V Sedova and S V Ivanov.....58

Heterostructures, superlattices and quantum wells

Intraband light absorption by holes in InGaAsP/InP quantum wells

N V Pavlov and G G Zegrya.....64

Structural and optical characteristics of GaAs films grown on Si/Ge substrates

A V Rykov, M V Dorokhin, P S Vergeles, N V Baidus, V A Kovalskiy, E B Yakimov and O A Soltanovich.....69

Anomalous Nernst-Ettingshausen effect in $\delta\text{Mn}/\text{GaAs}/\text{InGaAs}$ ferromagnetic semiconductor heterostructures

Yu M Kuznetsov, M V Dorokhin, A V Kudrin and O V Vikhrova.....73

Non-equilibrium hole capture to excited acceptor states in quantum wells due to optical scattering

G R Balakhtar, A N Sofronov, M Ya Vinnichenko, D A Firsov and L E Vorobjev.....78

Impurity-assisted terahertz photoluminescence in quantum wells under conditions of interband stimulated emission

I S Makhov, V Yu Panevin, D A Firsov, L E Vorobjev, A N Sofronov, M Ya Vinnichenko, N A Maleev and A P Vasil'ev.....83

The development of technology for growing InAs/GaSb superlattices by MOCVD

I V Fedorov, R V Levin and V N Nevedomsky.....87

Quantum dots, quantum wires and other low-dimensional systems

Particle binding over a nanofiber

I D Toftul, D F Kornovan and M I Petrov.....91

Ring resonator optical modes in InGaN/GaN structures grown on micro-cone-patterned sapphire substrates

D R Kazanov, G Pozina, V N Jmerik and T V Shubina.....98

Misfit stress relaxation in composite core-shell nanowires with parallelepiped cores using rectangular prismatic dislocation loops

S A Krasnitckii, D R Kolomoetc, A M Smirnov and M Yu Gutkin.....102

Spontaneous parametric downconversion of light by a dielectric nanoparticle

N A Olekhno, M I Petrov and I V Iorsh.....107

Optical properties of blue-green single-photon sources based on self-assembled CdSe quantum dots

M V Rakhlin, K G Belyaev, S V Sorokin, I S Mukhin, S V Ivanov and A A Toropov.....113

Synthesis of optosensitive structures based on zinc oxide

A A Ryabko, A I Maximov, V A Moshnikov and S S Nalimova.....118

Investigation of the influence of geometric parameters of carbon nanotube arrays on their adhesion properties

M V Il'ina, A A Konshin, O I Il'in, N N Rudyk, A A Fedotov and O A Ageev.....124

Conductive atomic force microscopy study of the photoexcitation effect on resistive switching in ZrO₂(Y) films with Au nanoparticles

A S Novikov, D O Filatov, D A Antonov, I N Antonov, M E Shenina and O N Gorshkov.....129

Optoelectronics and nanoelectronics devices

Photoelectron scattering in a *p*-GaN(Cs,O) photocathode

S A Rozhkov, V V Bakin, S N Kosolobov, H E Scheibler and A S Terekhov.....134

Bipolar resistive switching in metal-insulator-semiconductor nanostructures based on silicon nitride and silicon oxide

M N Koryazhkina, S V Tikhov, A N Mikhaylov, A I Belov, D S Korolev, I N Antonov, V V Karzanov, O N Gorshkov, D I Tetelbaum, P Karakolis and P Dimitrakis.....141

Study of PV characteristics of Al_xGa_{1-x}As/GaAs photodiodes

V S Kalinovskiy, E V Kontrosh, G A Gusev, A N Sumarokov, G V Klimko, S V Ivanov, V S Yuferev, T S Tabarov and V M Andreev.....148

Investigating the effect of silicon surface chemical treatment on Al/Si contact properties in GaP/Si solar cells

D Kudryashov and A Gudovskikh.....156

Quantum-cascade lasers in the 7-8 μm spectral range with full top metallization

A S Kurochkin, A V Babichev, D V Denisov, L Ya Karachinsky, I I Novikov, A N Sofronov, D A Firsov, L E Vorobjev, A Bousseksou and A Yu Egorov.....160

Photoactive n-type oxide AZO-AgNP-AZO multilayer films for photovoltaic application

E V Shirshneva-Vaschenko, T G Liashenko, P S Shirshnev, V E Bougov and A E Romanov.....164

A study of the influence of forward bias pulse duration on the switching process of a 4H-SiC drift step recovery diode

A A Smirnov and S A Shevchenko.....170

Influence of interface layer preparation on the electrical and spectral characteristics of GaN/Si solar cells

K U Shugurov, A M Mozharov, G A Sapunov, V V Fedorov, A D Bolshakov and I S Mukhin.....174

Simulation of charge transport in micro and nanoscale FETs with elements having different dielectric properties

A M Blokhin, E A Kruglova and B V Semisalov.....179

New connecting elements for cascade photoelectric converters based on InP

A E Marichev, B V Pushnyi, R V Levin, N M Lebedeva, N D Prasolov and E V Kontrosh.....186

Ultraviolet light-emitting diodes and photodiodes grown by plasma-assisted molecular beam epitaxy

D V Nechaev, E A Evropeytsev, A N Semenov, S I Troshkov, V I Egorkin, V E Zemlyakov, M V Rzheutski, E V Lutsenko, A A Toropov, S V Ivanov and V N Jmerik.....190

ECV profiling of GaAs and GaN HEMT heterostructures

G Yakovlev and V Zubkov.....195

Study and optimization of heterojunction silicon solar cells

N A Chuchvaga, D V Zhilina, S R Zhantuarov, S Zh Tokmoldin, E I Terukov and N S Tokmoldin.....201

New materials

Internal friction in particulate composites of $(x)\text{Mn}_{0.4}\text{Zn}_{0.6}\text{Fe}_2\text{O}_4 - (1-x)\text{PbZr}_{0.53}\text{Ti}_{0.47}\text{O}_3$ in the vicinity of the structural phase transition temperatures

A V Kalgin and S A Gridnev.....208